

**Features:**

- Isolated mounting base 4000V~
 - Pressure contact technology with Increased power cycling capability
 - Space and weight saving
- Typical Applications**
- Various rectifiers
 - DC supply for PWM inverter

V_{RRM}	Type & Outline		
	MDx400-26-406F3	MDx400-28-406F3	MDx400-30-406F3
2600V			
2800V			
3000V			
3200V			
3400V			
3600V			
3600V	MD400-36-406F3G		

MDx stands for any type of **MDC**, **MDA**, **MDK**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_J(°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _C =60°C	150			400	A
I _{F(RMS)}	RMS forward current					628	A
I _{RRM}	Repetitive peak current	at V _{RRM}	150			35	mA
I _{FSM}	Surge forward current	V _R =60%V _{RRM} , t=10ms half sine	150			8.1	kA
I ² t	I ² t for fusing coordination					328	10 ³ A ² s
V _{FO}	Threshold voltage		150			0.95	V
r _F	Forward slope resistance					1.05	mΩ
V _{FM}	Peak forward voltage	I _{FM} =1200A	25			2.41	V
R _{th(j-c)}	Thermal resistance Junction to case	Single side cooled per chip				0.11	°C/W
R _{th(c-h)}	Thermal resistance case to heatsink	Single side cooled per chip				0.04	°C/W
V _{iso}	Isolation voltage	50Hz,R.M.S,t=1min,I _{iso} :1mA(MAX)		4000			V
F _m	Terminal connection torque(M12)			12		14	N·m
	Mounting torque(M6)			4.5		6.0	N·m
T _{vj}	Junction temperature			-40		150	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				1580		g
Outline				406F3			

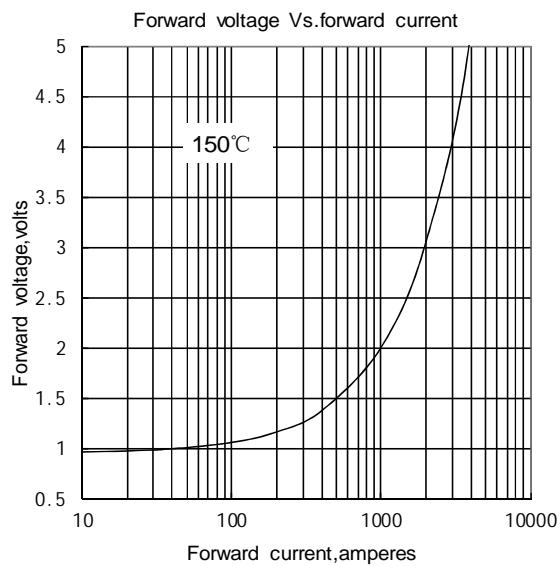


Fig.1

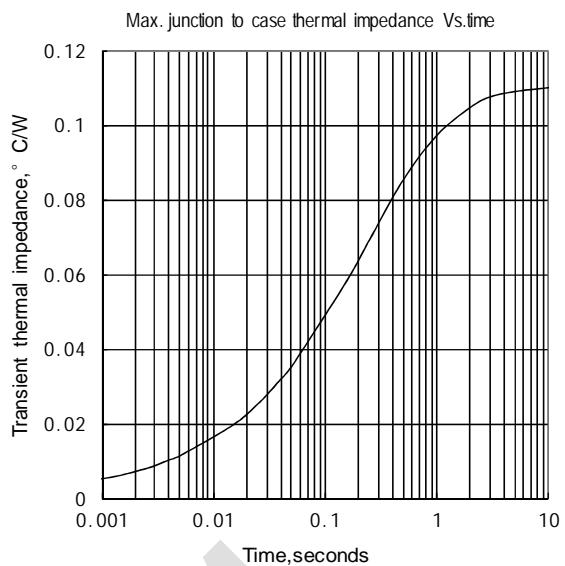


Fig.2

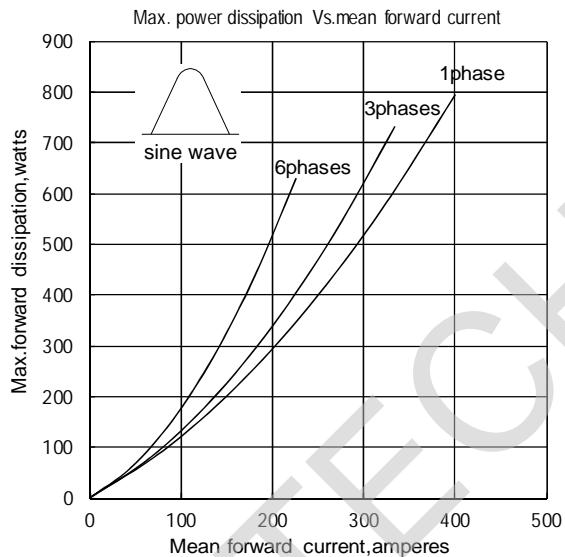


Fig.3

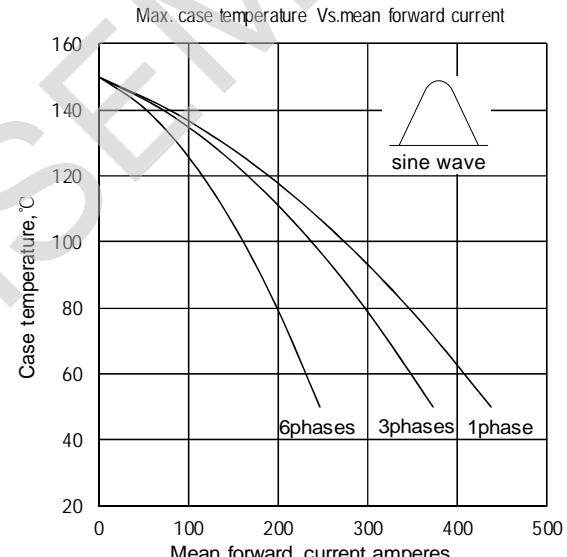


Fig.4

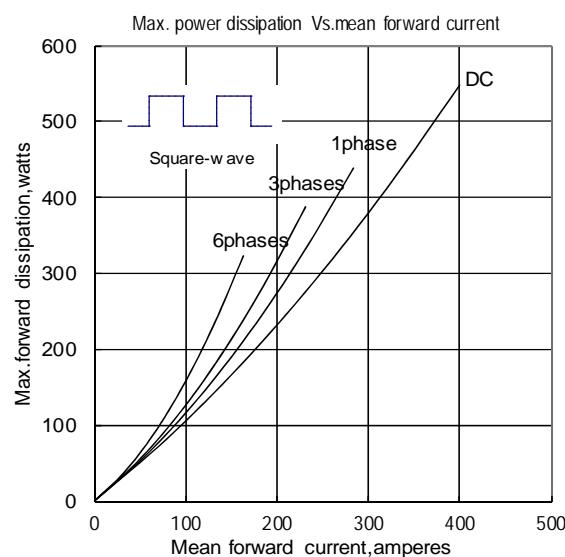


Fig.5

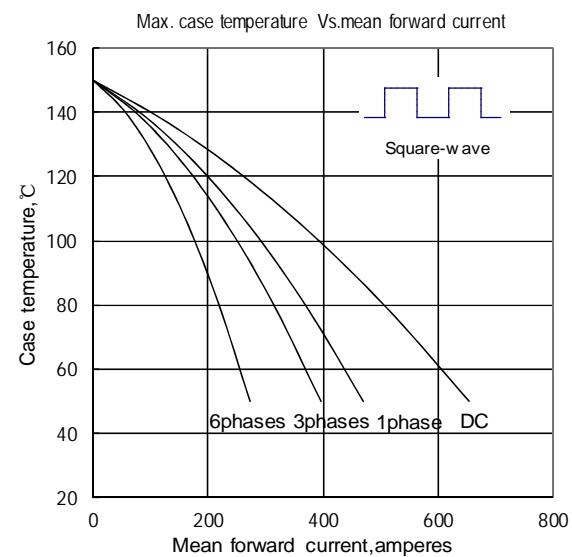


Fig.6

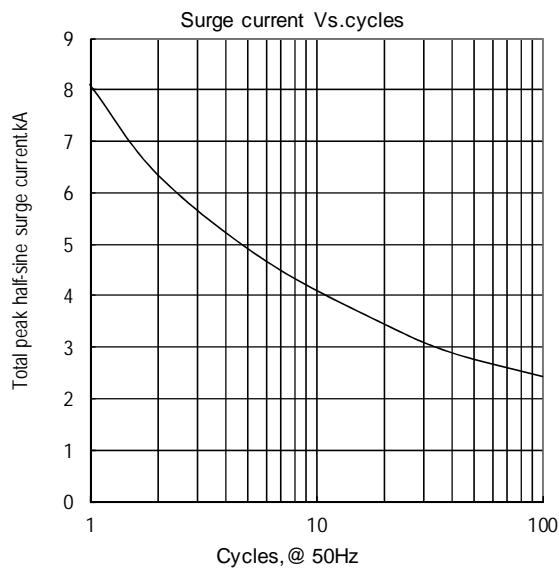


Fig.7

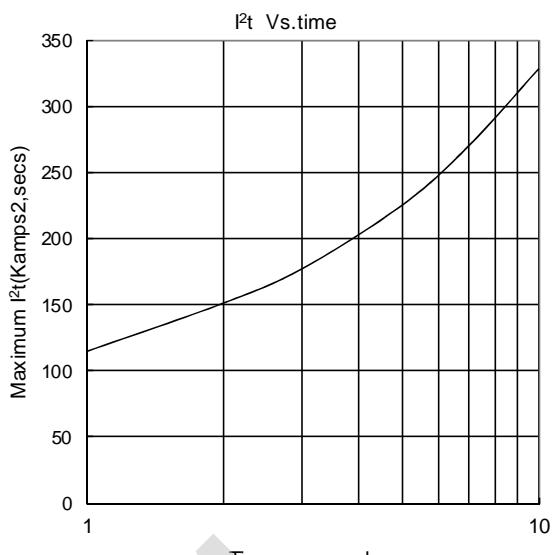
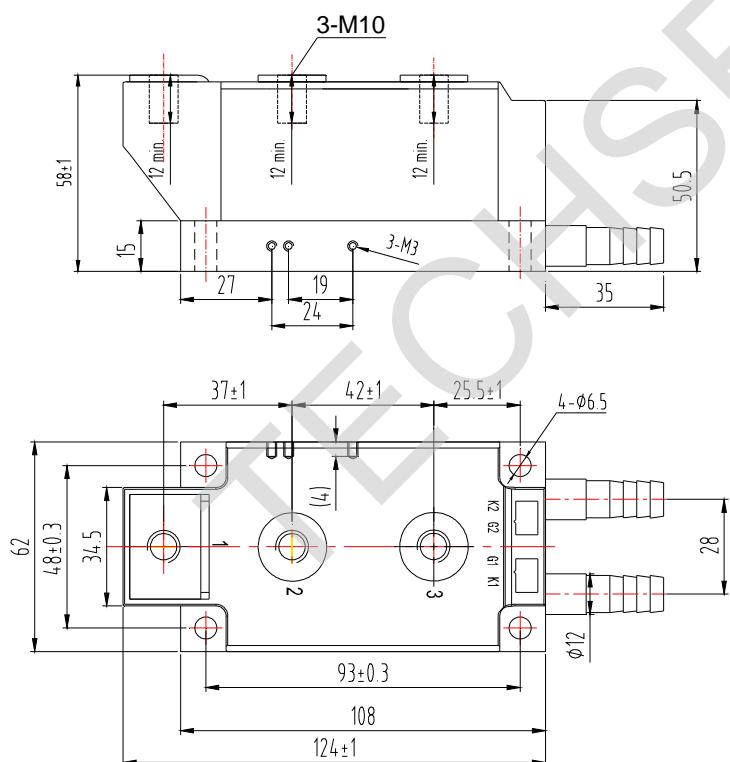
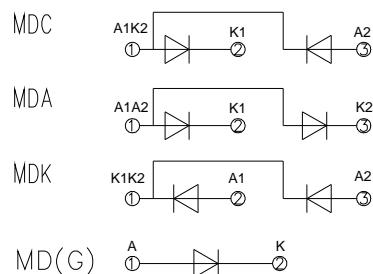
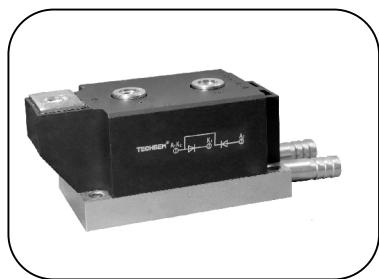


Fig.8

Outline:Unmarked dimensional tolerance: $\pm 0.5\text{mm}$ 

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V_{RRM}	Type & Outline		
	800V	1000V	1200V
1400V	MDx500-14-406F3		
1600V	MDx500-16-406F3		
1800V	MDx500-18-406F3		
1800V	MD500-18-406F3G		

MDx stands for any type of **MDC**, **MDA**, **MDK**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_J(°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _C =60°C	150			500	A
I _{F(RMS)}	RMS forward current					785	A
I _{RRM}	Repetitive peak current	at V _{RRM}	150			40	mA
I _{FSM}	Surge forward current	V _R =60%V _{RRM} , t=10ms half sine,	150			15	kA
I ² t	I ² t for fusing coordination					1125	10 ³ A ² s
V _{FO}	Threshold voltage		150			0.75	V
r _F	Forward slope resistance					0.51	mΩ
V _{FM}	Peak forward voltage	I _{FM} =1500A	25			1.66	V
R _{th(j-c)}	Thermal resistance Junction to case	Single side cooled per chip				0.13	°C/W
R _{th(c-h)}	Thermal resistance case to heatsink	Single side cooled per chip				0.04	°C/W
V _{iso}	Isolation voltage	50Hz,R.M.S,t=1min,I _{iso} :1mA(MAX)		3000			V
F _m	Terminal connection torque(M12)			12		14	N·m
	Mounting torque(M6)			4.5		6.0	N·m
T _{vj}	Junction temperature			-40		150	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				1580		g
Outline				406F3			

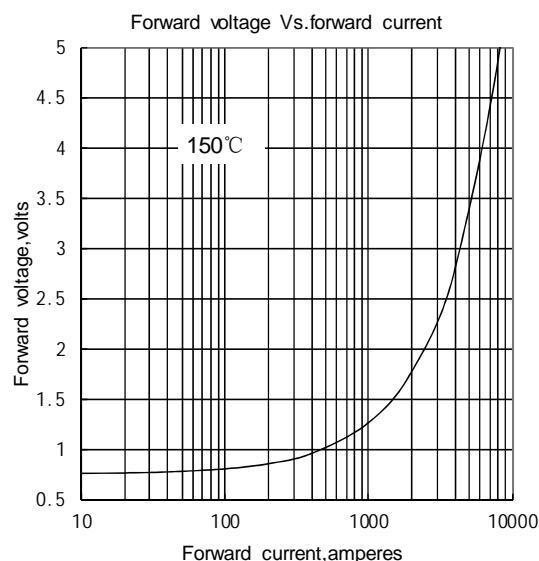


Fig.1

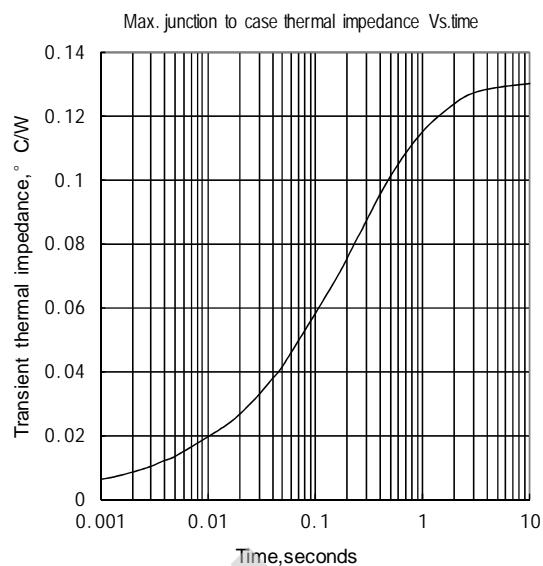


Fig.2

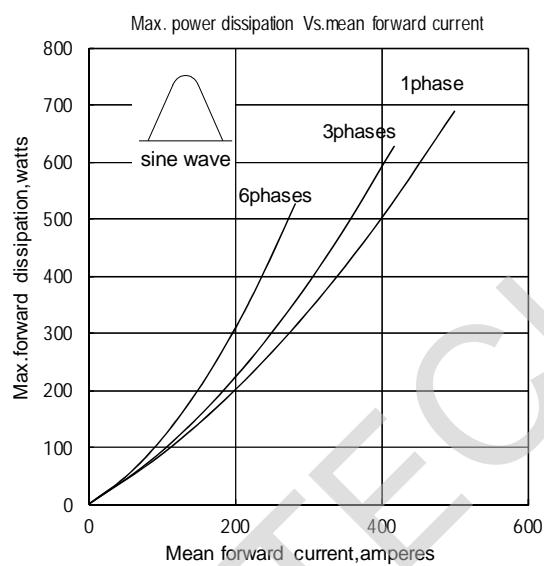


Fig.3

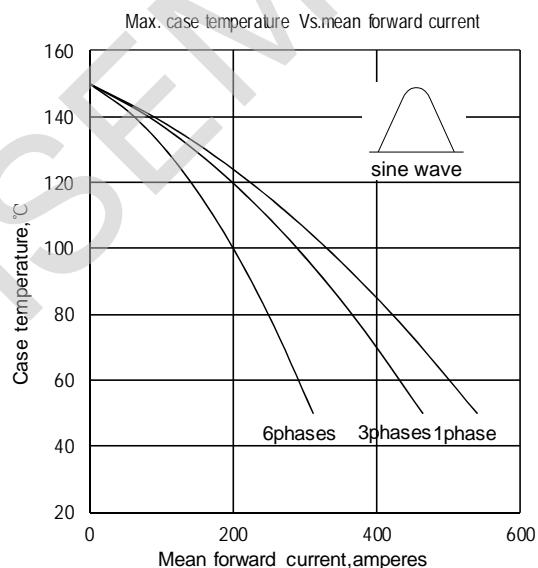


Fig.4

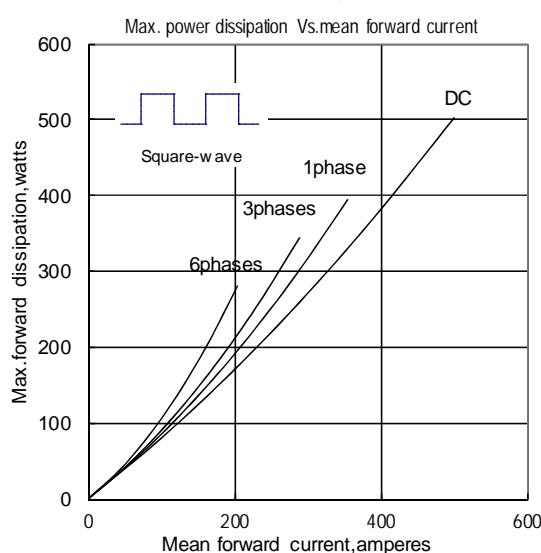


Fig.5

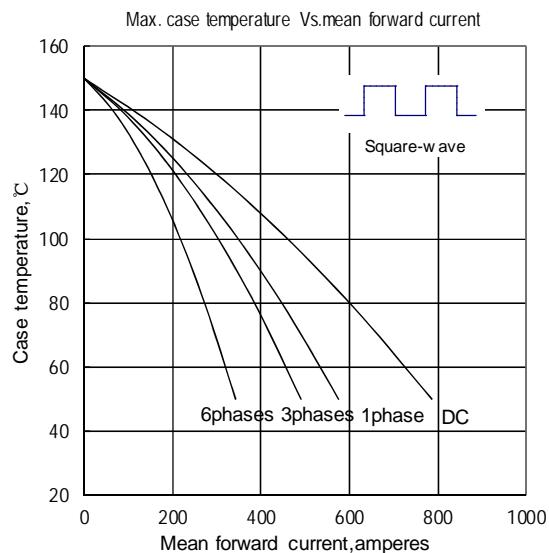


Fig.6

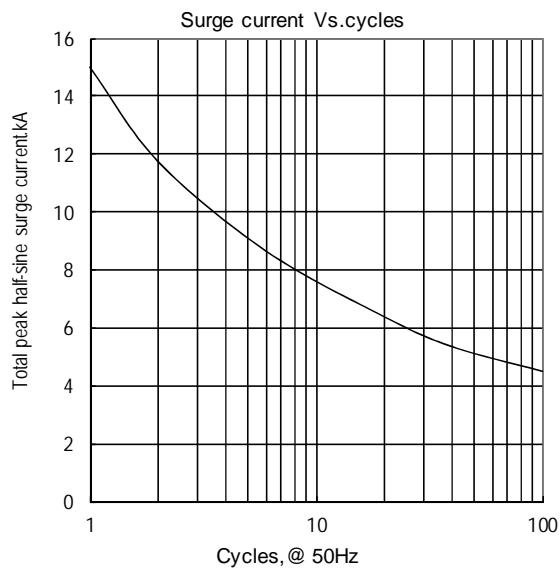


Fig.7

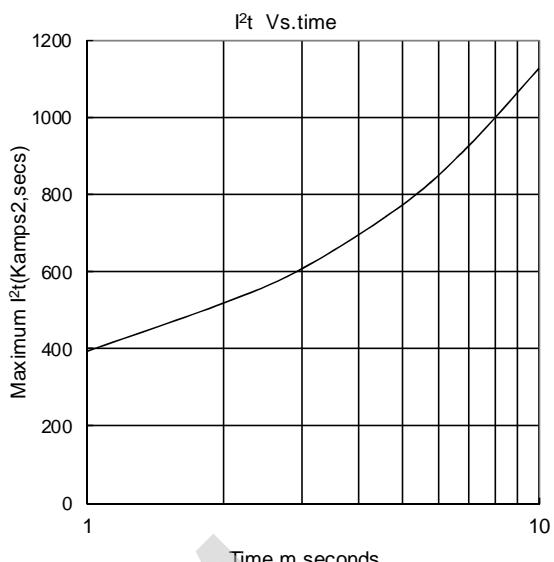
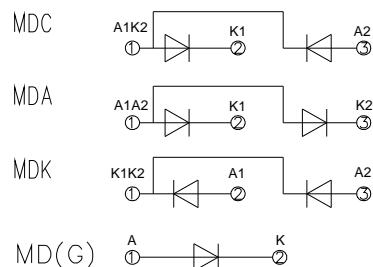
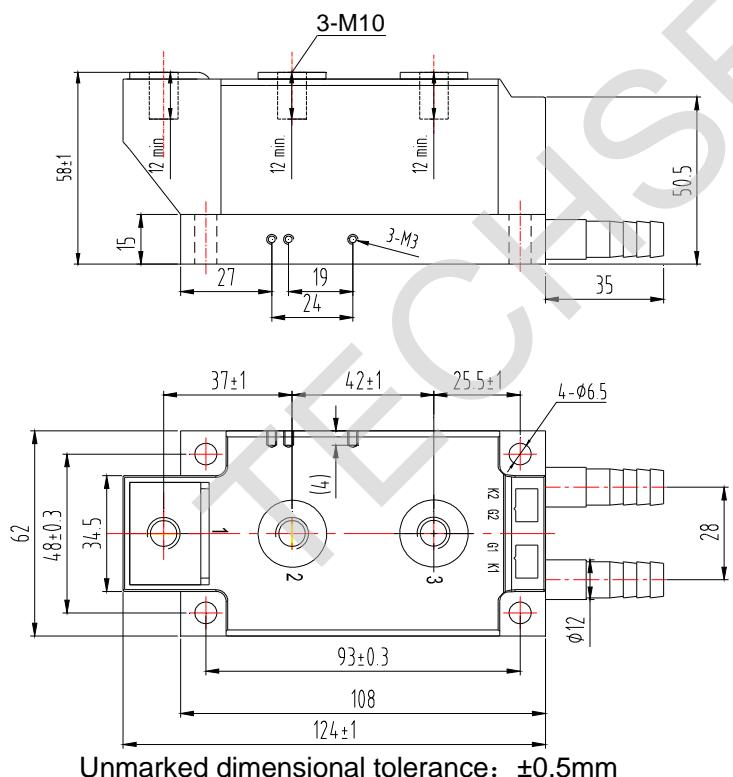
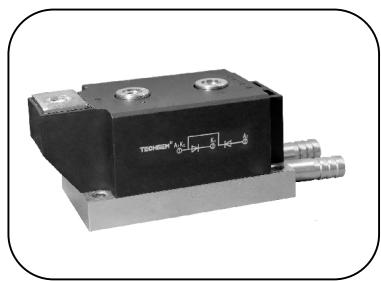


Fig.8

Outline:

**Features:**

- Isolated mounting base 3000V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving

Typical Applications

- Various rectifiers
- DC supply for PWM inverter

V_{RRM}	Type & Outline		
	Min	Type	Max
2000V		MDx500-20-406F3	
2200V		MDx500-22-406F3	
2500V		MDx500-25-406F3	
2500V		MD500-25-406F3G	

MDx stands for any type of **MDC**, **MDA**, **MDK**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_J(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, $T_c=60^{\circ}C$	150			500	A
$I_{F(RMS)}$	RMS forward current					785	A
I_{RRM}	Repetitive peak current	at V_{RRM}	150			40	mA
I_{FSM}	Surge forward current	$V_R=60\%V_{RRM}$, $t=10ms$ half sine	150			12	kA
I^2t	I^2t for fusing coordination					720	10^3A^2s
V_{FO}	Threshold voltage		150			0.85	V
r_F	Forward slope resistance					0.53	$m\Omega$
V_{FM}	Peak forward voltage	$I_{FM}=1500A$	25			1.80	V
$R_{th(j-c)}$	Thermal resistance Junction to case	Single side cooled per chip				0.12	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance case to heatsink	Single side cooled per chip				0.04	$^{\circ}C/W$
V_{iso}	Isolation voltage	50Hz,R.M.S., $t=1min$, $I_{iso}:1mA(MAX)$		3000			V
F_m	Terminal connection torque(M12)			12		14	$N\cdot m$
	Mounting torque(M6)			4.5		6.0	$N\cdot m$
T_{vj}	Junction temperature			-40		150	$^{\circ}C$
T_{stg}	Stored temperature			-40		125	$^{\circ}C$
W_t	Weight				1580		g
Outline				406F3			

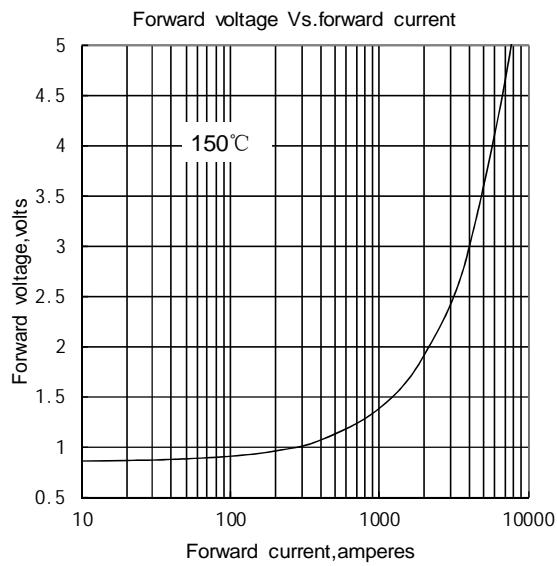


Fig.1

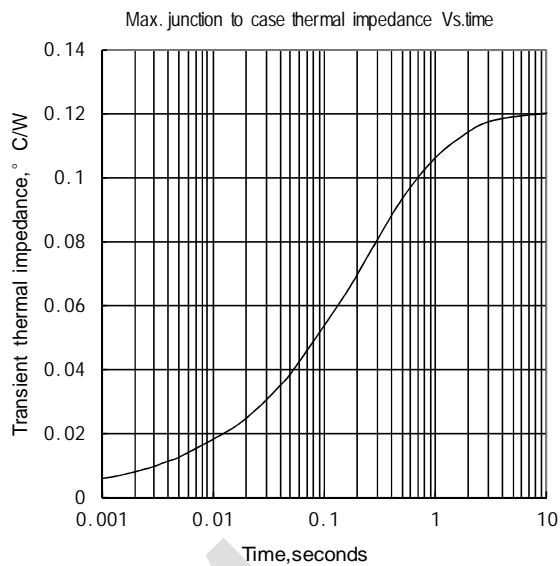


Fig.2

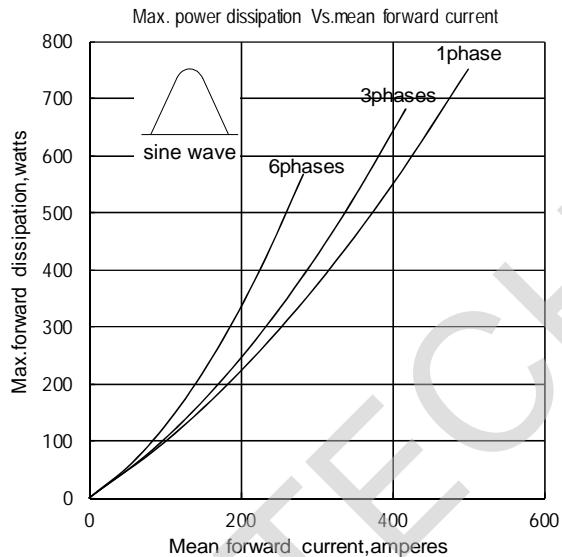


Fig.3

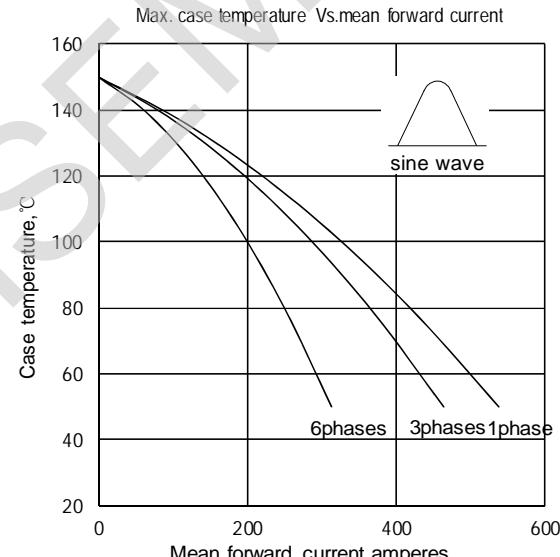


Fig.4

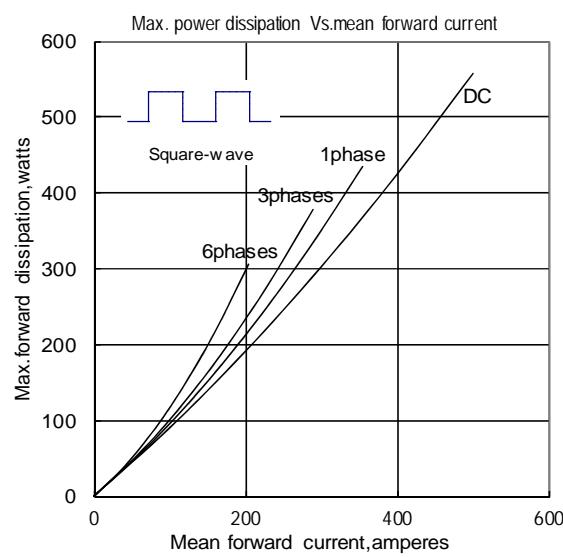


Fig.5

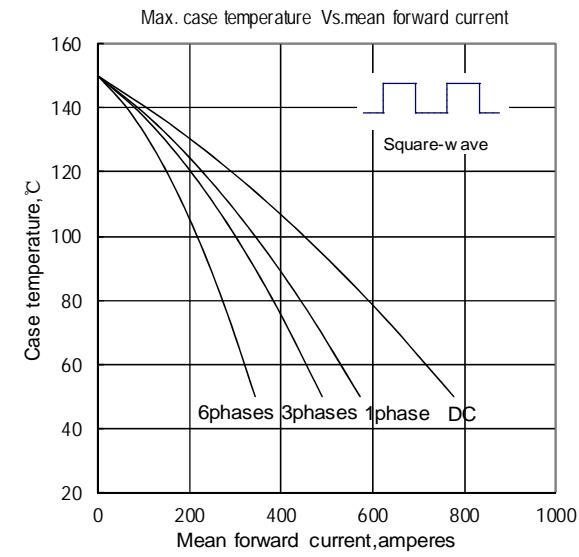


Fig.6

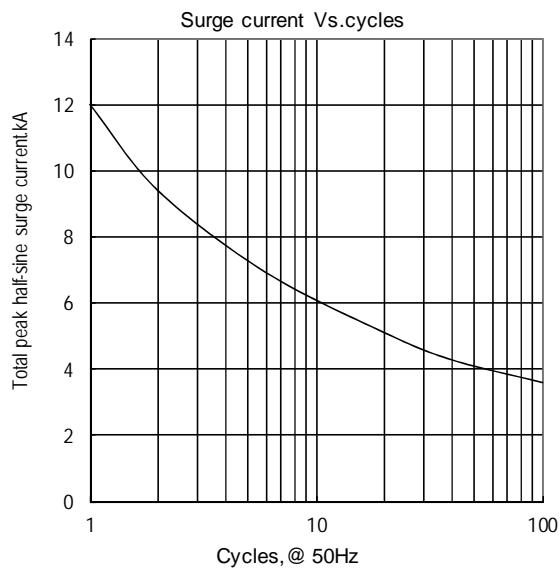


Fig.7

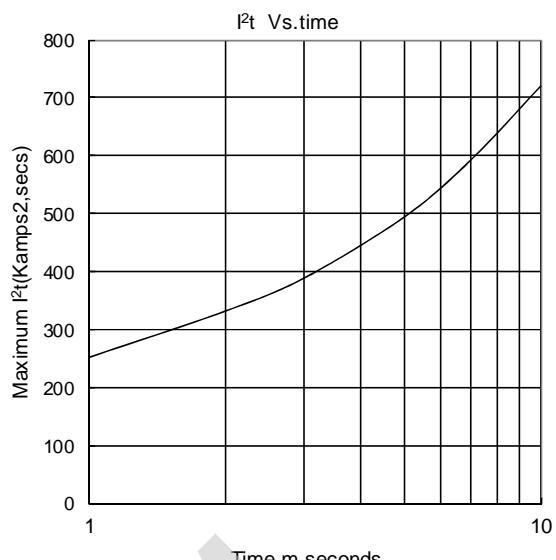
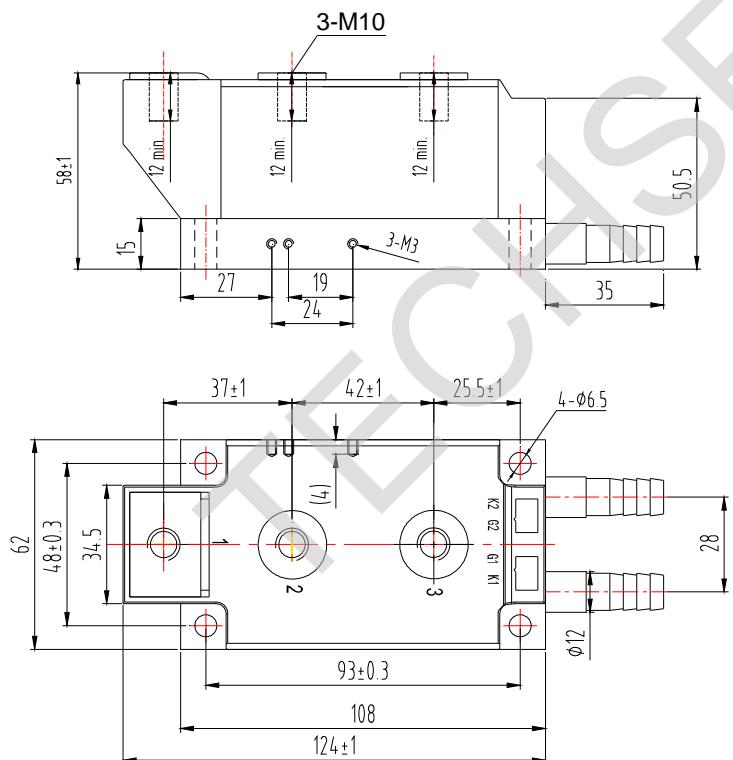
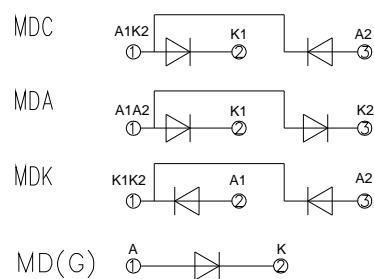
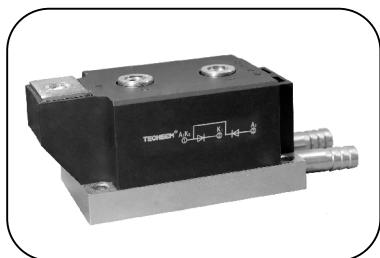


Fig.8

Outline:

Unmarked dimensional tolerance: ±0.5mm



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V_{RRM}	Type & Outline		
	800V	1000V	1200V
1400V	MDx600-14-406F3	MDx600-14-406F3	MDx600-14-406F3
1600V	MDx600-16-406F3	MDx600-16-406F3	MDx600-16-406F3
1800V	MDx600-18-406F3	MDx600-18-406F3	MDx600-18-406F3
1800V	MD600-18-406F3G		

MDx stands for any type of **MDC**, **MDA**, **MDK**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_J(°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _C =60°C	150			600	A
I _{F(RMS)}	RMS forward current					942	A
I _{RRM}	Repetitive peak current	at V _{RRM}	150			40	mA
I _{FSM}	Surge forward current	V _R =60%V _{RRM} , t=10ms half sine	150			16.1	kA
I ² t	I ² t for fusing coordination					1296	10 ³ A ² s
V _{FO}	Threshold voltage		150			0.75	V
r _F	Forward slope resistance					0.42	mΩ
V _{FM}	Peak forward voltage	I _{FM} =1800A	25			1.65	V
R _{th(j-c)}	Thermal resistance Junction to case	Single side cooled per chip				0.11	°C/W
R _{th(c-h)}	Thermal resistance case to heatsink	Single side cooled per chip				0.04	°C/W
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1min, I _{iso} :1mA(MAX)		3000			V
F _m	Terminal connection torque(M12)			12		14	N·m
	Mounting torque(M6)			4.5		6.0	N·m
T _{vj}	Junction temperature			-40		150	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				1580		g
Outline				406F3			

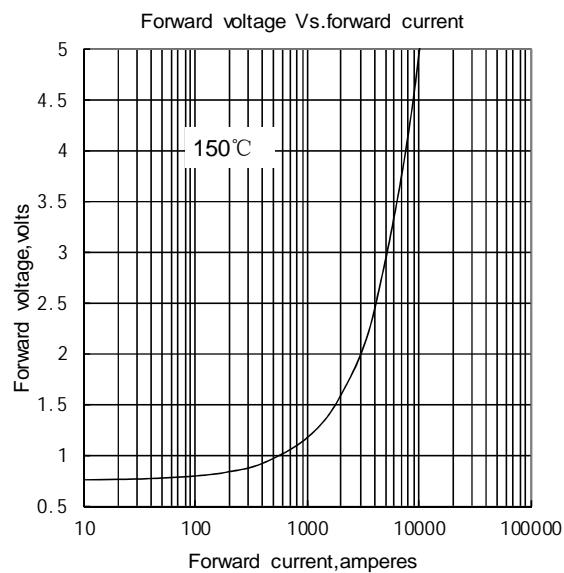


Fig.1

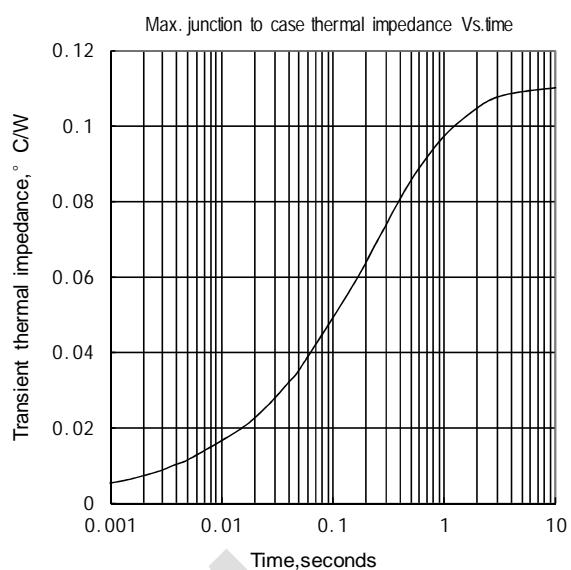


Fig.2

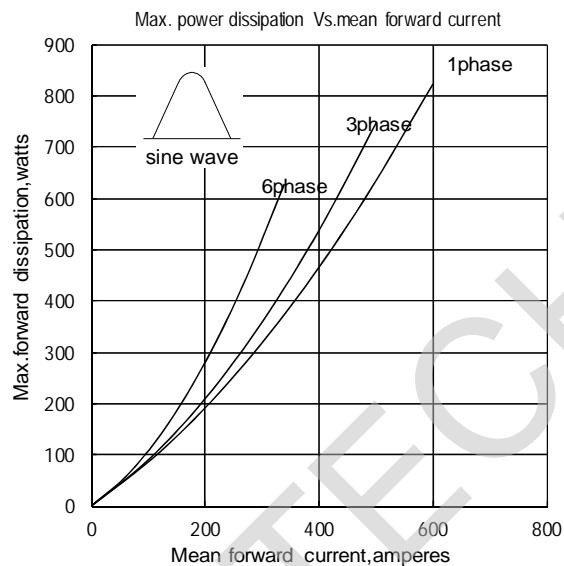


Fig.3

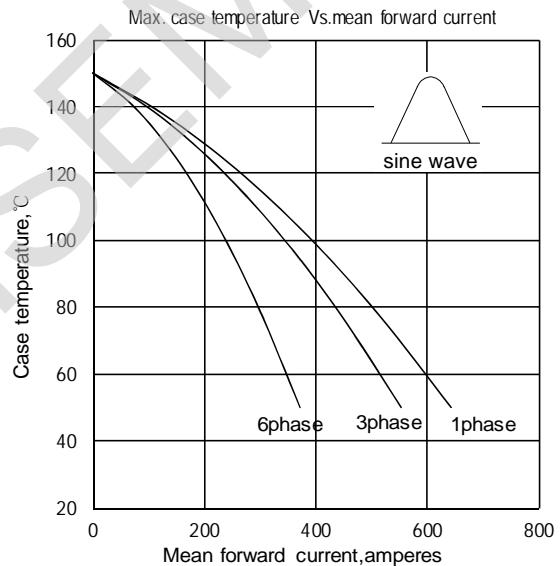


Fig.4

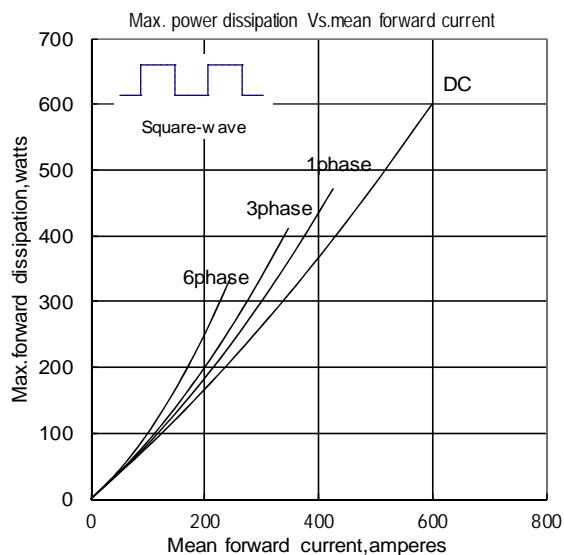


Fig.5

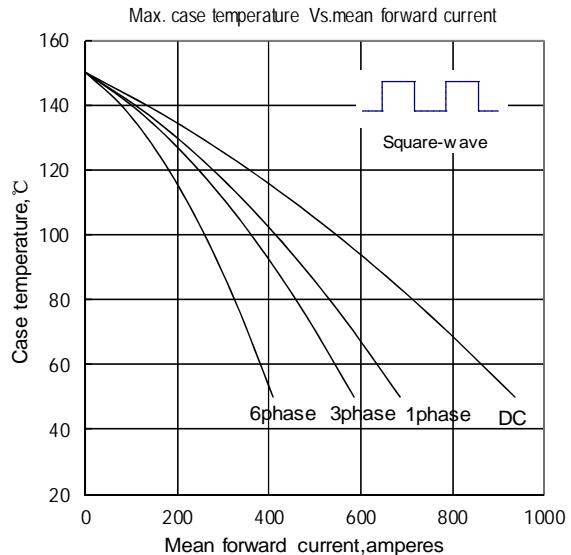


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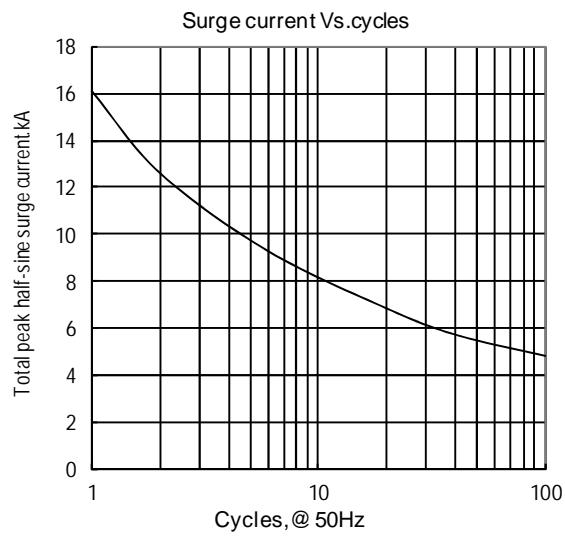


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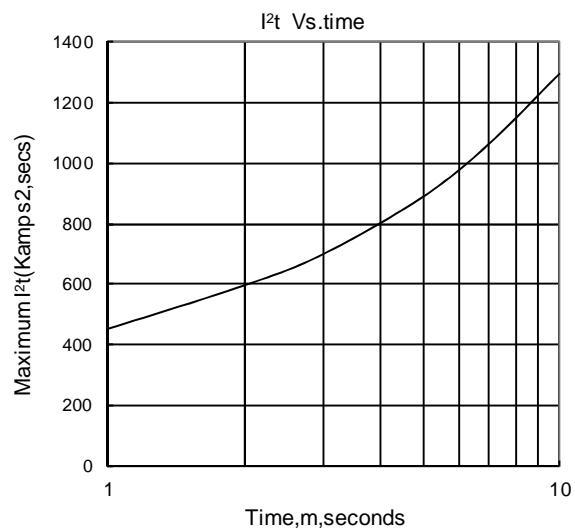
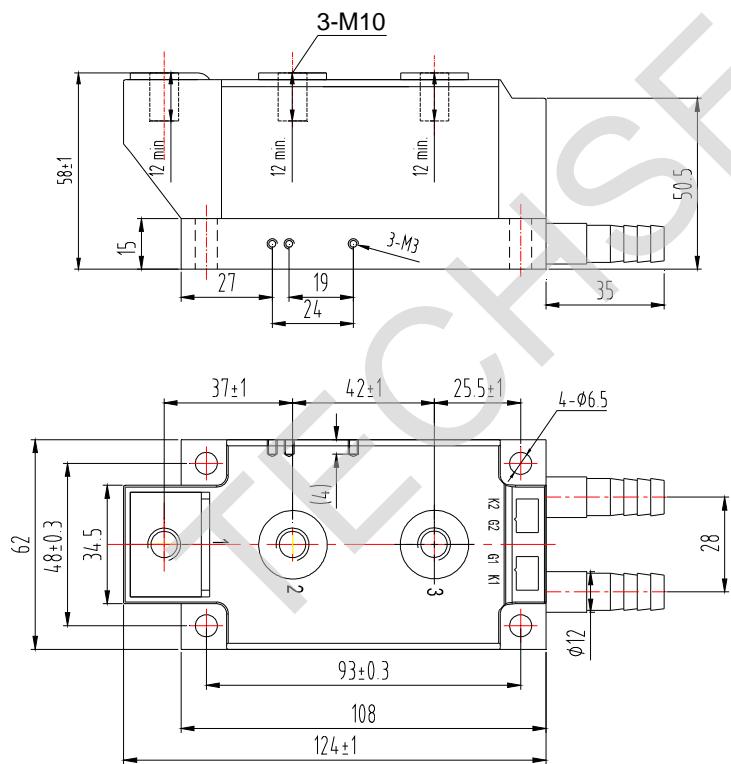


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Unmarked dimensional tolerance: ±0.5mm

